

BD136G, BD138G, BD140G

Plastic Medium-Power Silicon PNP Transistors

This series of plastic, medium-power silicon PNP transistors are designed for use as audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

Features

- High DC Current Gain
- BD 136, 138, 140 are complementary with BD 135, 137, 139
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BD136G BD138G BD140G	V_{CEO}	45 60 80	Vdc
Collector-Base Voltage BD136G BD138G BD140G	V_{CBO}	45 60 100	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current	I_C	1.5	Adc
Base Current	I_B	0.5	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.25 10	Watts mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	12.5 100	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	10	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	100	$^\circ\text{C/W}$

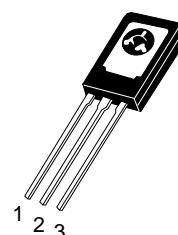
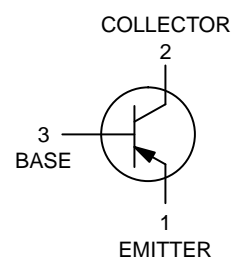
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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1.5 A POWER TRANSISTORS PNP SILICON 45, 60, 80 V, 12.5 W



TO-225
CASE 77
STYLE 1

MARKING DIAGRAM



Y = Year
WW = Work Week
xx = 36, 38, 40
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
BD136G	TO-225 (Pb-Free)	500 Units/Box
BD138G	TO-225 (Pb-Free)	500 Units/Box
BD140G	TO-225 (Pb-Free)	500 Units/Box

BD136G, BD138G, BD140G

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 0.03\text{ A}$, $I_B = 0$) BD136G BD138G BD140G	BV_{CEO}	45 60 80	– – –	Vdc
Collector Cutoff Current ($V_{CB} = 30\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 30\text{ Vdc}$, $I_E = 0$, $T_C = 125^\circ\text{C}$)	I_{CBO}	– –	0.1 10	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	10	μAdc
DC Current Gain ($I_C = 0.005\text{ A}$, $V_{CE} = 2\text{ V}$) ($I_C = 0.15\text{ A}$, $V_{CE} = 2\text{ V}$) ($I_C = 0.5\text{ A}$, $V_{CE} = 2\text{ V}$)	h_{FE}^*	25 40 25	– 250 –	–
Collector–Emitter Saturation Voltage (Note 1) ($I_C = 0.5\text{ A}$, $I_B = 0.05\text{ A}$)	$V_{CE(sat)}^*$	–	0.5	Vdc
Base–Emitter On Voltage (Note 1) ($I_C = 0.5\text{ A}$, $V_{CE} = 2.0\text{ Vdc}$)	$V_{BE(on)}^*$	–	1	Vdc

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

TYPICAL CHARACTERISTICS

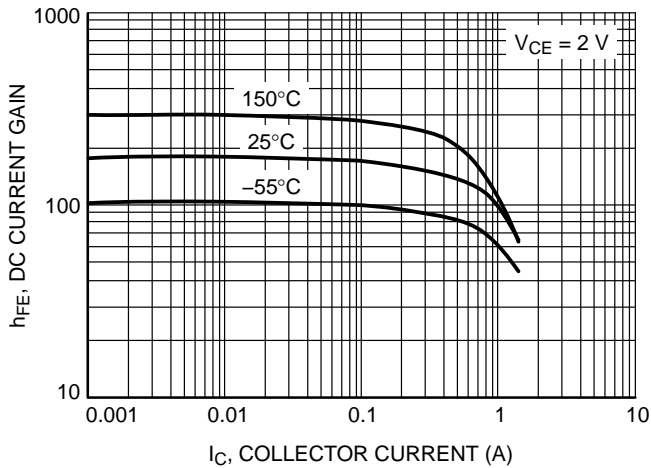


Figure 1. DC Current Gain

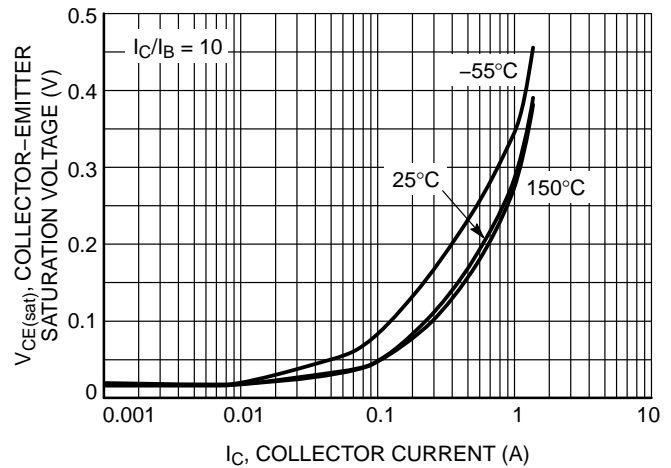


Figure 2. Collector–Emitter Saturation Voltage

BD136G, BD138G, BD140G

TYPICAL CHARACTERISTICS

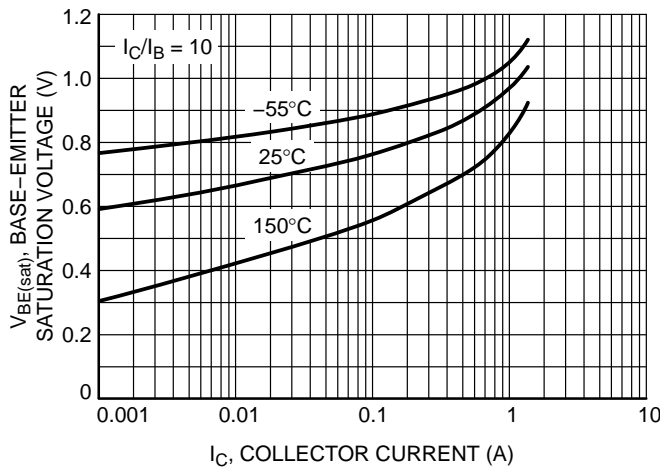


Figure 3. Base-Emitter Saturation Voltage

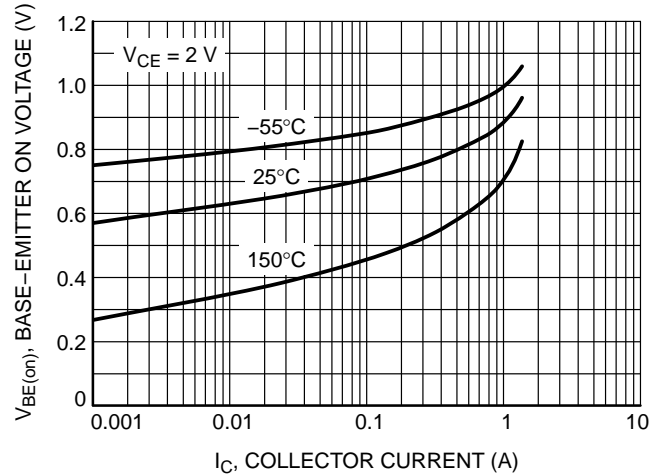


Figure 4. Base-Emitter On Voltage

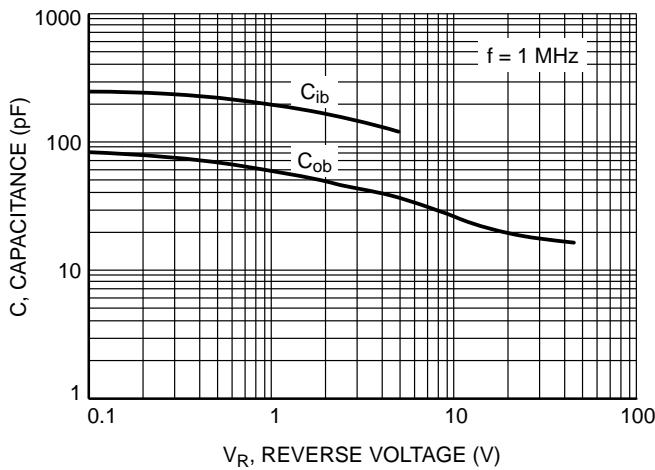


Figure 5. Capacitance

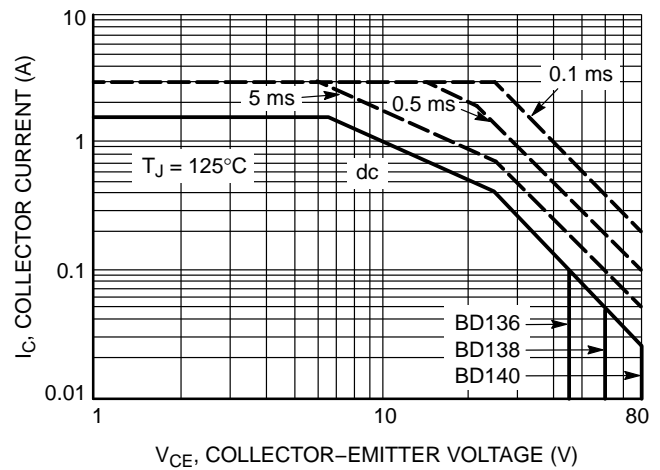


Figure 6. Active-Region Safe Operating Area

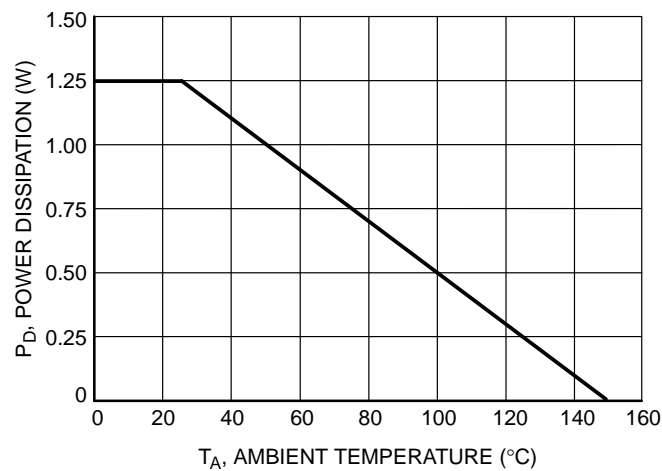
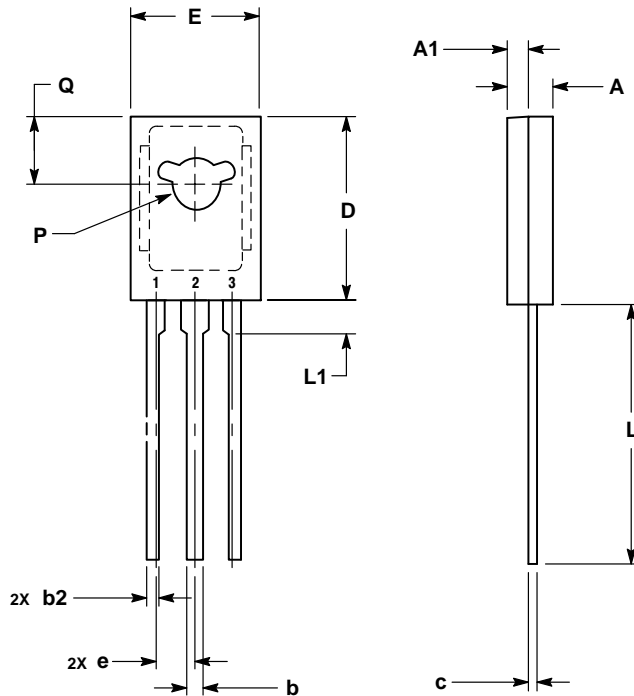


Figure 7. Power Derating

BD136G, BD138G, BD140G

PACKAGE DIMENSIONS


TO-225
CASE 77-09
ISSUE AB



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

DIM	MILLIMETERS	
	MIN	MAX
A	2.40	3.00
A1	1.00	1.50
b	0.60	0.90
b2	0.51	0.88
c	0.39	0.63
D	10.60	11.10
E	7.40	7.80
e	2.04	2.54
L	14.50	16.63
L1	1.27	2.54
P	2.90	3.30
Q	3.80	4.20

- STYLE 1:
- PIN 1. EMITTER
 - COLLECTOR
 - BASE

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